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ELECTRICAL BIASING OF GAS
INTRODUCTION MEANS OF PLASMA
APPARATUS

ABSTRACT OF THE DISCLOSURE

A method of treating or processing at least one substrate/workpiece in a plasma comprises steps of:

- (a) providing an apparatus comprising a chamber defining an interior space;
- 5 (b) mounting/positioning at least one substrate/workpiece in the interior space;
- (c) injecting gas(es) into the interior space by means of an electrically isolated gas supply means having at least one outlet orifice;
- (d) generating a plasma in the interior space;
- 10 (e) applying a bias potential to the gas supply means to suppress plasma formation at the at least one outlet orifice; and
- (f) treating/processing the at least one substrate/workpiece in the plasma.